









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- | GENERAL SWITCH CATALOG  |  |   |  |  |   |   |   |   |   |  |
|---|--|---|--|--|---|---|---|---|---|--|
| <b>33 mΩ, single</b><br> | TPS201xA<br><b>TPS202x</b><br>TPS203x                          | 0.2 A – 2 A<br><b>0.2 A – 2 A</b><br>0.2 A – 2 A      | <b>80 mΩ, dual</b><br>            | TPS2042<br>TPS2052<br>TPS2046<br>TPS2056                   | 500 mA<br>500 mA<br>250 mA<br>250 mA              | <b>80 mΩ, dual</b><br> | <b>80 mΩ, triple</b><br> | <b>80 mΩ, quad</b><br> | <b>80 mΩ, quad</b><br> |  |
| <b>80 mΩ, single</b><br> | TPS2014<br>TPS2015<br>TPS2041<br>TPS2051<br>TPS2045<br>TPS2055 | 600 mA<br>1 A<br>500 mA<br>500 mA<br>250 mA<br>250 mA | <b>260 mΩ</b><br><br><b>1.3 Ω</b> | TPS2100/1<br>IN1<br>IN2<br><br>TPS2102/3/4/5<br>IN1<br>IN2 | 500 mA<br>500 mA<br>10 mA<br><br>500 mA<br>100 mA | TPS2080<br>TPS2081<br>TPS2082<br>TPS2090<br>TPS2091<br>TPS2092  | 500 mA<br>500 mA<br>500 mA<br>250 mA<br>250 mA<br>250 mA  | TPS2043<br>TPS2053<br>TPS2047<br>TPS2057  | 500 mA<br>500 mA<br>250 mA<br>250 mA  |  |
|   |  |   |  |  |   |   |   | TPS2044<br>TPS2054<br>TPS2048<br>TPS2058  | 500 mA<br>500 mA<br>250 mA<br>250 mA  |  |
|   |  |   |  |  |   |   |   |   | TPS2085<br>TPS2086<br>TPS2087<br>TPS2095<br>TPS2096<br>TPS2097  | 500 mA<br>500 mA<br>500 mA<br>250 mA<br>250 mA<br>250 mA |

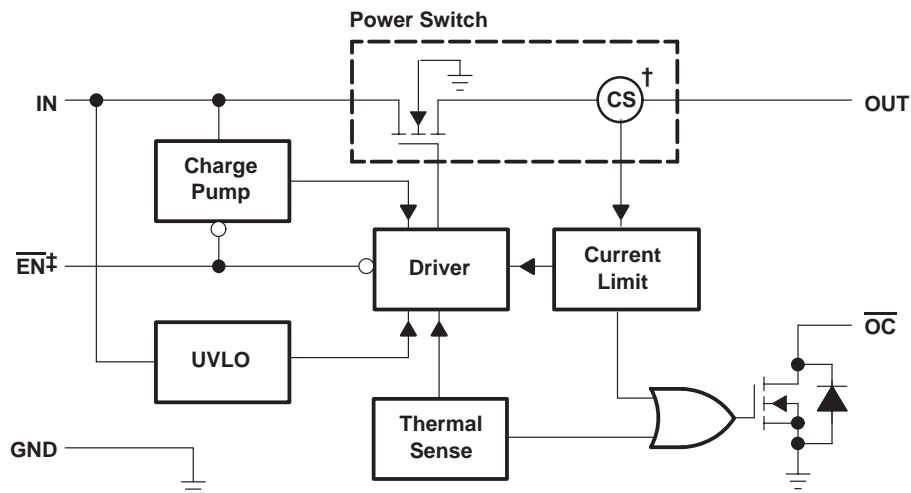
TPS2041A, TPS2042A, TPS2043A, TPS2044A  
TPS2051A, TPS2052A, TPS2053A, TPS2054A  
**CURRENT-LIMITED POWER-DISTRIBUTION SWITCHES**  
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AVAILABLE OPTIONS					
T <sub>A</sub>	ENABLE	RECOMMENDED MAXIMUM CONTINUOUS LOAD CURRENT (A)	TYPICAL SHORT-CIRCUIT CURRENT LIMIT AT 25°C (A)	NUMBER OF SWITCHES	PACKAGED DEVICES
					SOIC (D) <sup>†</sup>
0°C to 85°C	Active low	0.5	0.9	Single	TPS2041AD
	Active high				TPS2051AD
	Active low			Dual	TPS2042AD
	Active high				TPS2052AD
	Active low			Triple	TPS2043AD
	Active high				TPS2053AD
	Active low			Quad	TPS2044AD
	Active high				TPS2054AD

<sup>†</sup> The D package is available taped and reeled. Add an R suffix to device type (e.g., TPS2041ADR)

## functional block diagrams

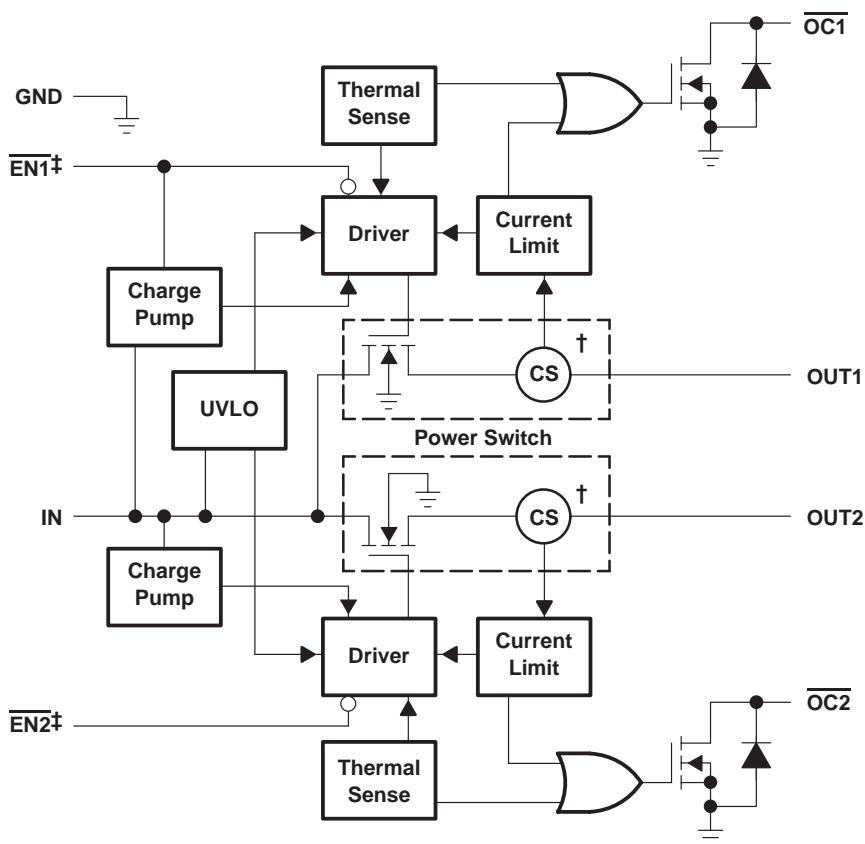
### TPS2041A



† Current sense

‡ Active high for TPS205xA series

### TPS2042A

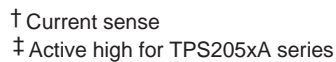


† Current sense

‡ Active high for TPS205xA series

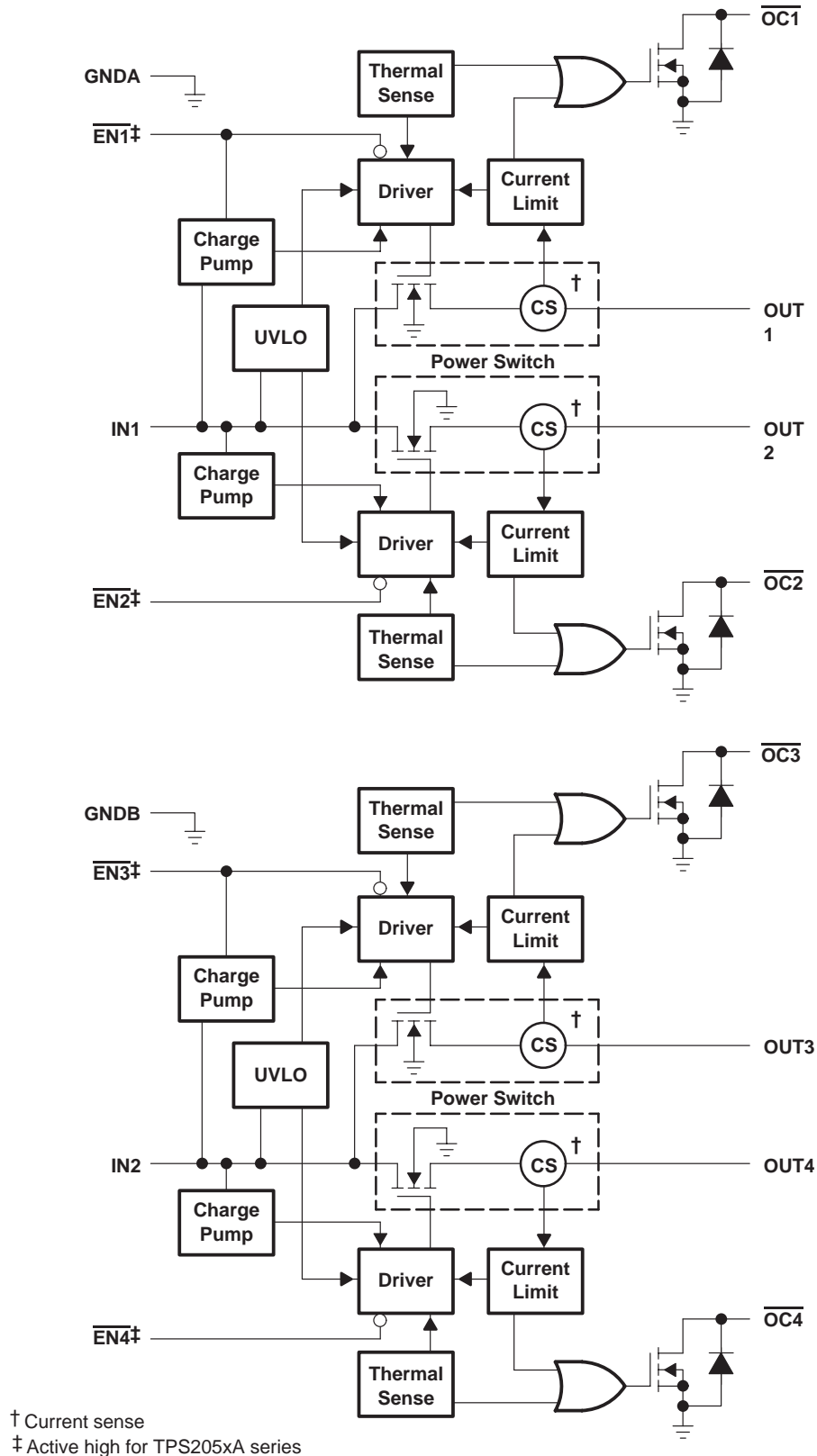
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## TPS2043A



functional block diagrams

TPS2044A



TPS2041A, TPS2042A, TPS2043A, TPS2044A  
TPS2051A, TPS2052A, TPS2053A, TPS2054A  
**CURRENT-LIMITED POWER-DISTRIBUTION SWITCHES**  
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**Terminal Functions**

**TPS2041A and TPS2051A**

TERMINAL			I/O	DESCRIPTION
NAME	NO.			
	TPS2041A	TPS2051A		
$\overline{\text{EN}}$	4	—	I	Enable input. Logic low turns on power switch.
EN	—	4	I	Enable input. Logic high turns on power switch.
GND	1	1	I	Ground
IN	2, 3	2, 3	I	Input voltage
$\overline{\text{OC}}$	5	5	O	Overcurrent. Logic output active low
OUT	6, 7, 8	6, 7, 8	O	Power-switch output

**TPS2042A and TPS2052A**

TERMINAL			I/O	DESCRIPTION
NAME	NO.			
	TPS2042A	TPS2052A		
$\overline{\text{EN1}}$	3	–	I	Enable input. Logic low turns on power switch, IN-OUT1.
$\overline{\text{EN2}}$	4	–	I	Enable input. Logic low turns on power switch, IN-OUT2.
EN1	–	3	I	Enable input. Logic high turns on power switch, IN-OUT1.
EN2	–	4	I	Enable input. Logic high turns on power switch, IN-OUT2.
GND	1	1	I	Ground
IN	2	2	I	Input voltage
$\overline{\text{OC1}}$	8	8	O	Overcurrent. Logic output active low, for power switch, IN-OUT1
$\overline{\text{OC2}}$	5	5	O	Overcurrent. Logic output active low, for power switch, IN-OUT2
OUT1	7	7	O	Power-switch output
OUT2	6	6	O	Power-switch output

TPS2041A, TPS2042A, TPS2043A, TPS2044A  
TPS2051A, TPS2052A, TPS2053A, TPS2054A  
**CURRENT-LIMITED POWER-DISTRIBUTION SWITCHES**  
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**Terminal Functions (Continued)**

**TPS2043A and TPS2053A**

TERMINAL			I/O	DESCRIPTION
NAME	NO.			
	TPS2043A	TPS2053A		
EN1	3	–	I	Enable input, logic low turns on power switch, IN1-OUT1.
EN2	4	–	I	Enable input, logic low turns on power switch, IN1-OUT2.
EN3	7	–	I	Enable input, logic low turns on power switch, IN2-OUT3.
EN1	–	3	I	Enable input, logic high turns on power switch, IN1-OUT1.
EN2	–	4	I	Enable input, logic high turns on power switch, IN1-OUT2.
EN3	–	7	I	Enable input, logic high turns on power switch, IN2-OUT3.
GNDA	1	1		Ground for IN1 switch and circuitry.
GNDB	5	5		Ground for IN2 switch and circuitry.
IN1	2	2	I	Input voltage
IN2	6	6	I	Input voltage
NC	8, 9, 10	8, 9, 10		No connection
OC1	16	16	O	Overcurrent, logic output active low, IN1-OUT1
OC2	13	13	O	Overcurrent, logic output active low, IN1-OUT2
OC3	12	12	O	Overcurrent, logic output active low, IN2-OUT3
OUT1	15	15	O	Power-switch output, IN1-OUT1
OUT2	14	14	O	Power-switch output, IN1-OUT2
OUT3	11	11	O	Power-switch output, IN2-OUT3

**TPS2044A and TPS2054A**

TERMINAL			I/O	DESCRIPTION
NAME	NO.			
	TPS2044A	TPS2054A		
EN1	3	—	I	Enable input. logic low turns on power switch, IN1-OUT1.
EN2	4	—	I	Enable input. Logic low turns on power switch, IN1-OUT2.
EN3	7	—	I	Enable input. Logic low turns on power switch, IN2-OUT3.
EN4	8	—	I	Enable input. Logic low turns on power switch, IN2-OUT4.
EN1	—	3	I	Enable input. Logic high turns on power switch, IN1-OUT1.
EN2	—	4	I	Enable input. Logic high turns on power switch, IN1-OUT2.
EN3	—	7	I	Enable input. Logic high turns on power switch, IN2-OUT3.
EN4	—	8	I	Enable input. Logic high turns on power switch, IN2-OUT4.
GNDA	1	1		Ground for IN1 switch and circuitry.
GNDB	5	5		Ground for IN2 switch and circuitry.
IN1	2	2	I	Input voltage
IN2	6	6	I	Input voltage
OC1	16	16	O	Overcurrent. Logic output active low, IN1-OUT1
OC2	13	13	O	Overcurrent. Logic output active low, IN1-OUT2
OC3	12	12	O	Overcurrent. Logic output active low, IN2-OUT3
OC4	9	9	O	Overcurrent. Logic output active low, IN2-OUT4
OUT1	15	15	O	Power-switch output, IN1-OUT1
OUT2	14	14	O	Power-switch output, IN1-OUT2
OUT3	11	11	O	Power-switch output, IN2-OUT3
OUT4	10	10	O	Power-switch output, IN2-OUT4

# TPS2041A, TPS2042A, TPS2043A, TPS2044A TPS2051A, TPS2052A, TPS2053A, TPS2054A CURRENT-LIMITED POWER-DISTRIBUTION SWITCHES

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## detailed description

### power switch

The power switch is an N-channel MOSFET with a maximum on-state resistance of 135 m $\Omega$  ( $V_{I(IN)} = 5$  V). Configured as a high-side switch, the power switch prevents current flow from OUT to IN and IN to OUT when disabled. The power switch supplies a minimum of 500 mA per switch.

### charge pump

An internal charge pump supplies power to the driver circuit and provides the necessary voltage to pull the gate of the MOSFET above the source. The charge pump operates from input voltages as low as 2.7 V and requires very little supply current.

### driver

The driver controls the gate voltage of the power switch. To limit large current surges and reduce the associated electromagnetic interference (EMI) produced, the driver incorporates circuitry that controls the rise times and fall times of the output voltage. The rise and fall times are typically in the 2-ms to 4-ms range.

### enable ( $\overline{ENx}$ , $ENx$ )

The logic enable disables the power switch and the bias for the charge pump, driver, and other circuitry to reduce the supply current. The supply current is reduced to less than 10  $\mu$ A on the single and dual devices (20  $\mu$ A on the triple and quad devices) when a logic high is present on  $\overline{ENx}$  (TPS204xA†) or a logic low is present on  $ENx$  (TPS205xA†). A logic zero input on  $\overline{ENx}$  or a logic high on  $ENx$  restores bias to the drive and control circuits and turns the power on. The enable input is compatible with both TTL and CMOS logic levels.

### overcurrent ( $\overline{OCx}$ )

The  $\overline{OCx}$  open-drain output is asserted (active low) when an overcurrent or overtemperature condition is encountered. The output will remain asserted until the overcurrent or overtemperature condition is removed.

### current sense

A sense FET monitors the current supplied to the load. The sense FET measures current more efficiently than conventional resistance methods. When an overload or short circuit is encountered, the current-sense circuitry sends a control signal to the driver. The driver in turn reduces the gate voltage and drives the power FET into its saturation region, which switches the output into a constant-current mode and holds the current constant while varying the voltage on the load.

### thermal sense

The TPS204xA and TPS205xA implement a dual-threshold thermal trip to allow fully independent operation of the power distribution switches. In an overcurrent or short-circuit condition the junction temperature rises. When the die temperature rises to approximately 140°C, the internal thermal sense circuitry checks to determine which power switch is in an overcurrent condition and turns off that switch, thus isolating the fault without interrupting operation of the adjacent power switch. Hysteresis is built into the thermal sense, and after the device has cooled approximately 20 degrees, the switch turns back on. The switch continues to cycle off and on until the fault is removed. The ( $\overline{OCx}$ ) open-drain output is asserted (active low) when overtemperature or overcurrent occurs.

### undervoltage lockout

A voltage sense circuit monitors the input voltage. When the input voltage is below approximately 2 V, a control signal turns off the power switch.

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† Product series designations TPS204x and TPS205x refer to devices presented in this data sheet and not necessarily to other TI devices numbered in this sequence.



TPS2041A, TPS2042A, TPS2043A, TPS2044A  
 TPS2051A, TPS2052A, TPS2053A, TPS2054A  
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**absolute maximum ratings over operating free-air temperature range (unless otherwise noted)†**

Input voltage range, $V_{I(IN)}$ (see Note 1)	–0.3 V to 6 V
Output voltage range, $V_{O(OUT)}$ (see Note 1)	–0.3 V to $V_{I(IN)} + 0.3$ V
Input voltage range, $V_{I(ENx)}$ or $V_{I(ENx)}$	–0.3 V to 6 V
Continuous output current, $I_{O(OUT)}$	internally limited
Continuous total power dissipation	See Dissipation Rating Table
Operating virtual junction temperature range, $T_J$	0°C to 125°C
Storage temperature range, $T_{stg}$	–65°C to 150°C
Lead temperature soldering 1,6 mm (1/16 inch) from case for 10 seconds	260°C
Electrostatic discharge (ESD) protection: Human body model MIL-STD-883C	2 kV
Machine model	0.2 kV

† Stresses beyond those listed under “absolute maximum ratings” may cause permanent damage to the device. These are stress ratings only, and functional operation of the device at these or any other conditions beyond those indicated under “recommended operating conditions” is not implied. Exposure to absolute-maximum-rated conditions for extended periods may affect device reliability.

NOTE 1: All voltages are with respect to GND.

**DISSIPATION RATING TABLE**

PACKAGE	$T_A \leq 25^\circ\text{C}$ POWER RATING	DERATING FACTOR ABOVE $T_A = 25^\circ\text{C}$	$T_A = 70^\circ\text{C}$ POWER RATING	$T_A = 85^\circ\text{C}$ POWER RATING
D–8	725 mW	5.9 mW/°C	464 mW	377 mW
D–16	1123 mW	9 mW/°C	719 mW	584 mW

**recommended operating conditions**

	MIN	MAX	UNIT
Input voltage, $V_{I(IN)}$	2.7	5.5	V
Input voltage, $V_{I(EN)}$ or $V_{I(EN)}$	0	5.5	V
Continuous output current, $I_{O(OUT)}$ (per switch)	0	500	mA
Operating virtual junction temperature, $T_J$	0	125	°C

TPS2041A, TPS2042A, TPS2043A, TPS2044A  
 TPS2051A, TPS2052A, TPS2053A, TPS2054A  
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electrical characteristics over recommended operating junction temperature range,  $V_{I(IN)} = 5.5\text{ V}$ ,  $I_O = \text{rated current}$ ,  $V_{I(EN)} = 0\text{ V}$ ,  $V_{I(EN)} = V_{I(IN)}$  (unless otherwise noted)

power switch

PARAMETER		TEST CONDITION†	TPS204xA			TPS205xA			UNIT
			MIN	TYP	MAX	MIN	TYP	MAX	
$r_{DS(on)}$	Static drain-source on-state resistance, 5-V operation	$V_{I(IN)} = 5\text{ V}$ , $T_J = 25^\circ\text{C}$ , $I_O = 0.5\text{ A}$		80	100		80	100	$m\Omega$
		$V_{I(IN)} = 5\text{ V}$ , $T_J = 85^\circ\text{C}$ , $I_O = 0.5\text{ A}$		90	120		90	120	
		$V_{I(IN)} = 5\text{ V}$ , $T_J = 125^\circ\text{C}$ , $I_O = 0.5\text{ A}$		100	135		100	135	
	Static drain-source on-state resistance, 3.3-V operation	$V_{I(IN)} = 3.3\text{ V}$ , $T_J = 25^\circ\text{C}$ , $I_O = 0.5\text{ A}$		90	125		90	125	
		$V_{I(IN)} = 3.3\text{ V}$ , $T_J = 85^\circ\text{C}$ , $I_O = 0.5\text{ A}$		110	145		110	145	
		$V_{I(IN)} = 3.3\text{ V}$ , $T_J = 125^\circ\text{C}$ , $I_O = 0.5\text{ A}$		120	160		120	160	
$t_r$	Rise time, output	$V_{I(IN)} = 5.5\text{ V}$ , $T_J = 25^\circ\text{C}$ , $C_L = 1\text{ }\mu\text{F}$ , $R_L = 10\text{ }\Omega$		2.5			2.5		ms
		$V_{I(IN)} = 2.7\text{ V}$ , $T_J = 25^\circ\text{C}$ , $C_L = 1\text{ }\mu\text{F}$ , $R_L = 10\text{ }\Omega$		3			3		
$t_f$	Fall time, output	$V_{I(IN)} = 5.5\text{ V}$ , $T_J = 25^\circ\text{C}$ , $C_L = 1\text{ }\mu\text{F}$ , $R_L = 10\text{ }\Omega$		4.4			4.4		ms
		$V_{I(IN)} = 2.7\text{ V}$ , $T_J = 25^\circ\text{C}$ , $C_L = 1\text{ }\mu\text{F}$ , $R_L = 10\text{ }\Omega$		2.5			2.5		

† Pulse-testing techniques maintain junction temperature close to ambient temperature; thermal effects must be taken into account separately.

enable input  $\overline{ENx}$  or  $ENx$

PARAMETER		TEST CONDITIONS	TPS204xA			TPS205xA			UNIT
			MIN	TYP	MAX	MIN	TYP	MAX	
$V_{IH}$	High-level input voltage	$2.7\text{ V} \leq V_{I(IN)} \leq 5.5\text{ V}$	2			2			V
$V_{IL}$	Low-level input voltage	$4.5\text{ V} \leq V_{I(IN)} \leq 5.5\text{ V}$			0.8			0.8	V
		$2.7\text{ V} \leq V_{I(IN)} \leq 4.5\text{ V}$			0.4			0.4	
$I_I$	Input current	TPS204xA $V_{I(ENx)} = 0\text{ V}$ or $V_{I(ENx)} = V_{I(IN)}$	-0.5		0.5				$\mu\text{A}$
		TPS205xA $V_{I(ENx)} = V_{I(IN)}$ or $V_{I(ENx)} = 0\text{ V}$				-0.5		0.5	
$t_{on}$	Turnon time	$C_L = 100\text{ }\mu\text{F}$ , $R_L = 10\text{ }\Omega$			20			20	ms
$t_{off}$	Turnoff time	$C_L = 100\text{ }\mu\text{F}$ , $R_L = 10\text{ }\Omega$			40			40	

current limit

PARAMETER		TEST CONDITIONS†	TPS204xA			TPS205xA			UNIT
			MIN	TYP	MAX	MIN	TYP	MAX	
$I_{OS}$	Short-circuit output current	$V_{I(IN)} = 5\text{ V}$ , OUT connected to GND, Device enabled into short circuit	0.7	1	1.3	0.7	1	1.3	A

† Pulse-testing techniques maintain junction temperature close to ambient temperature; thermal effects must be taken into account separately.

TPS2041A, TPS2042A, TPS2043A, TPS2044A  
TPS2051A, TPS2052A, TPS2053A, TPS2054A  
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electrical characteristics over recommended operating junction temperature range,  $V_{I(IN)} = 5.5\text{ V}$ ,  $I_O$  = rated current,  $V_{I(EN)} = 0\text{ V}$ ,  $V_{I(EN)} = V_{I(IN)}$  (unless otherwise noted) (continued)

**supply current (TPS2041A, TPS2051A)**

PARAMETER	TEST CONDITIONS			TPS2041A			TPS2051A			UNIT
				MIN	TYP	MAX	MIN	TYP	MAX	
Supply current, low-level output	No Load on OUT	$\overline{V_{I(EN)}} = V_{I(IN)}$	$T_J = 25^\circ\text{C}$	0.025	1					$\mu\text{A}$
			$-40^\circ\text{C} \leq T_J \leq 125^\circ\text{C}$		10					
		$V_{I(EN)} = 0\text{ V}$	$T_J = 25^\circ\text{C}$				0.025	1		
			$-40^\circ\text{C} \leq T_J \leq 125^\circ\text{C}$					10		
Supply current, high-level output	No Load on OUT	$\overline{V_{I(EN)}} = 0\text{ V}$	$T_J = 25^\circ\text{C}$	85	110					$\mu\text{A}$
			$-40^\circ\text{C} \leq T_J \leq 125^\circ\text{C}$	100						
		$V_{I(EN)} = V_{I(IN)}$	$T_J = 25^\circ\text{C}$				85	110		
			$-40^\circ\text{C} \leq T_J \leq 125^\circ\text{C}$				100			
Leakage current	OUT connected to ground	$\overline{V_{I(EN)}} = V_{I(IN)}$	$-40^\circ\text{C} \leq T_J \leq 125^\circ\text{C}$	100						$\mu\text{A}$
		$V_{I(EN)} = 0\text{ V}$	$-40^\circ\text{C} \leq T_J \leq 125^\circ\text{C}$				100			$\mu\text{A}$
Reverse leakage current	IN = High impedance	$\overline{V_{I(EN)}} = 0\text{ V}$	$T_J = 25^\circ\text{C}$	0.3						$\mu\text{A}$
		$V_{I(EN)} = V_{I(IN)}$					0.3			

**supply current (TPS2042A, TPS2052A)**

PARAMETER	TEST CONDITIONS			TPS2042A			TPS2052A			UNIT
				MIN	TYP	MAX	MIN	TYP	MAX	
Supply current, low-level output	No Load on OUT	$\overline{V_{I(ENx)}} = V_{I(IN)}$	$T_J = 25^\circ\text{C}$	0.025	1					$\mu\text{A}$
			$-40^\circ\text{C} \leq T_J \leq 125^\circ\text{C}$		10					
		$V_{I(ENx)} = 0\text{ V}$	$T_J = 25^\circ\text{C}$				0.025	1		
			$-40^\circ\text{C} \leq T_J \leq 125^\circ\text{C}$					10		
Supply current, high-level output	No Load on OUT	$\overline{V_{I(ENx)}} = 0\text{ V}$	$T_J = 25^\circ\text{C}$	85	110					$\mu\text{A}$
			$-40^\circ\text{C} \leq T_J \leq 125^\circ\text{C}$	100						
		$V_{I(ENx)} = V_{I(IN)}$	$T_J = 25^\circ\text{C}$				85	110		
			$-40^\circ\text{C} \leq T_J \leq 125^\circ\text{C}$				100			
Leakage current	OUT connected to ground	$\overline{V_{I(ENx)}} = V_{I(IN)}$	$-40^\circ\text{C} \leq T_J \leq 125^\circ\text{C}$	100						$\mu\text{A}$
		$V_{I(ENx)} = 0\text{ V}$	$-40^\circ\text{C} \leq T_J \leq 125^\circ\text{C}$				100			$\mu\text{A}$
Reverse leakage current	IN = high impedance	$\overline{V_{I(EN)}} = 0\text{ V}$	$T_J = 25^\circ\text{C}$	0.3						$\mu\text{A}$
		$V_{I(EN)} = V_{I(IN)}$					0.3			

TPS2041A, TPS2042A, TPS2043A, TPS2044A  
 TPS2051A, TPS2052A, TPS2053A, TPS2054A  
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electrical characteristics over recommended operating junction temperature range,  $V_{I(IN)} = 5.5\text{ V}$ ,  $I_O = \text{rated current}$ ,  $V_{I(EN)} = 0\text{ V}$ ,  $V_{I(EN)} = V_{I(IN)}$  (unless otherwise noted) (continued)

supply current (TPS2043A, TPS2053A)

PARAMETER	TEST CONDITIONS			TPS2043A			TPS2053A			UNIT
				MIN	TYP	MAX	MIN	TYP	MAX	
Supply current, low-level output	No Load on OUTx	$\overline{V_{I(ENx)}} = V_{I(INx)}$	$T_J = 25^\circ\text{C}$	0.05	2					$\mu\text{A}$
			$-40^\circ\text{C} \leq T_J \leq 125^\circ\text{C}$		20					
		$V_{I(ENx)} = 0\text{ V}$	$T_J = 25^\circ\text{C}$				0.05	2		
			$-40^\circ\text{C} \leq T_J \leq 125^\circ\text{C}$					20		
Supply current, high-level output	No Load on OUTx	$V_{I(ENx)} = 0\text{ V}$	$T_J = 25^\circ\text{C}$	160	200					$\mu\text{A}$
			$-40^\circ\text{C} \leq T_J \leq 125^\circ\text{C}$	200						
		$V_{I(ENx)} = V_{I(INx)}$	$T_J = 25^\circ\text{C}$				160	200		
			$-40^\circ\text{C} \leq T_J \leq 125^\circ\text{C}$				200			
Leakage current	OUTx connected to ground	$\overline{V_{I(ENx)}} = V_{I(INx)}$	$-40^\circ\text{C} \leq T_J \leq 125^\circ\text{C}$	200						$\mu\text{A}$
		$V_{I(ENx)} = 0\text{ V}$	$-40^\circ\text{C} \leq T_J \leq 125^\circ\text{C}$				200			
Reverse leakage current	IN = high impedance	$V_{I(ENx)} = 0\text{ V}$	$T_J = 25^\circ\text{C}$	0.3						$\mu\text{A}$
		$V_{I(ENx)} = V_{I(IN)}$					0.3			

supply current (TPS2044A, TPS2054A)

PARAMETER	TEST CONDITIONS			TPS2044A			TPS2054A			UNIT
				MIN	TYP	MAX	MIN	TYP	MAX	
Supply current, low-level output	No Load on OUTx	$\overline{V_{I(ENx)}} = V_{I(INx)}$	$T_J = 25^\circ\text{C}$	0.05	2					$\mu\text{A}$
			$-40^\circ\text{C} \leq T_J \leq 125^\circ\text{C}$		20					
		$V_{I(ENx)} = 0\text{ V}$	$T_J = 25^\circ\text{C}$				0.05	2		
			$-40^\circ\text{C} \leq T_J \leq 125^\circ\text{C}$					20		
Supply current, high-level output	No Load on OUTx	$\overline{V_{I(ENx)}} = 0\text{ V}$	$T_J = 25^\circ\text{C}$	170	220					$\mu\text{A}$
			$-40^\circ\text{C} \leq T_J \leq 125^\circ\text{C}$	200						
		$V_{I(ENx)} = V_{I(INx)}$	$T_J = 25^\circ\text{C}$				170	220		
			$-40^\circ\text{C} \leq T_J \leq 125^\circ\text{C}$				200			
Leakage current	OUTx connected to ground	$\overline{V_{I(ENx)}} = V_{I(INx)}$	$-40^\circ\text{C} \leq T_J \leq 125^\circ\text{C}$	200						$\mu\text{A}$
		$V_{I(ENx)} = 0\text{ V}$	$-40^\circ\text{C} \leq T_J \leq 125^\circ\text{C}$				200			
Reverse leakage current	IN = high impedance	$V_{I(EN)} = 0\text{ V}$	$T_J = 25^\circ\text{C}$	0.3						$\mu\text{A}$
		$V_{I(EN)} = V_{I(IN)}$					0.3			

undervoltage lockout

PARAMETER	TEST CONDITIONS	TPS204xA			TPS205xA			UNIT
		MIN	TYP	MAX	MIN	TYP	MAX	
Low-level input voltage		2		2.5	2		2.5	V
Hysteresis	$T_J = 25^\circ\text{C}$		100			100		mV

overcurrent  $\overline{OC}$

PARAMETER	TEST CONDITIONS	TPS204xA			TPS205xA			UNIT
		MIN	TYP	MAX	MIN	TYP	MAX	
Sink current <sup>†</sup>	$V_O = 5\text{ V}$			10			10	mA
Output low voltage	$I_O = 5\text{ V}$ , $\overline{V_{OL(OC)}}$			0.5			0.5	V
Off-state current <sup>†</sup>	$V_O = 5\text{ V}$ , $V_O = 3.3\text{ V}$			1			1	$\mu\text{A}$

<sup>†</sup> Specified by design, not production tested.

## PARAMETER MEASUREMENT INFORMATION

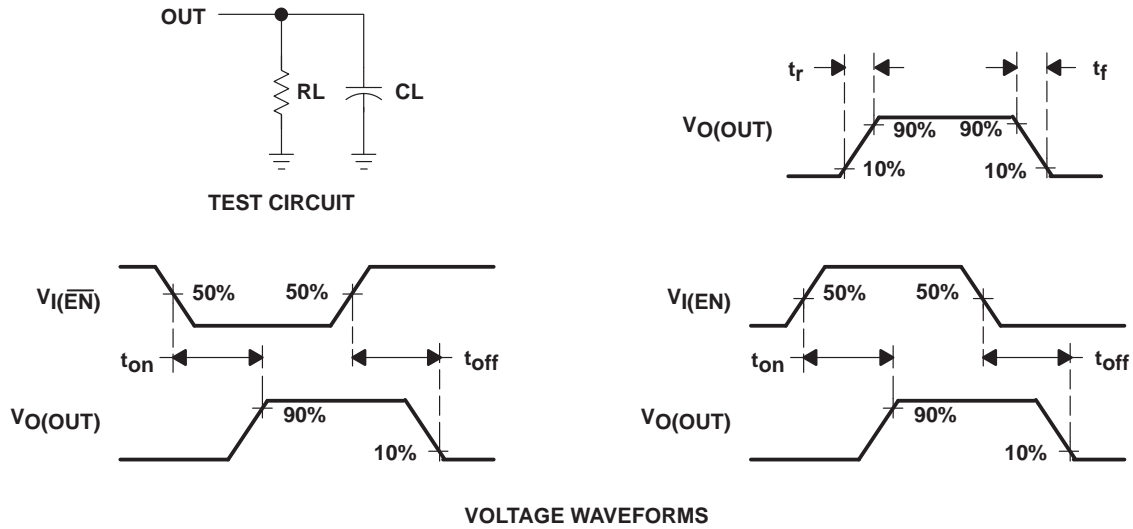


Figure 1. Test Circuit and Voltage Waveforms

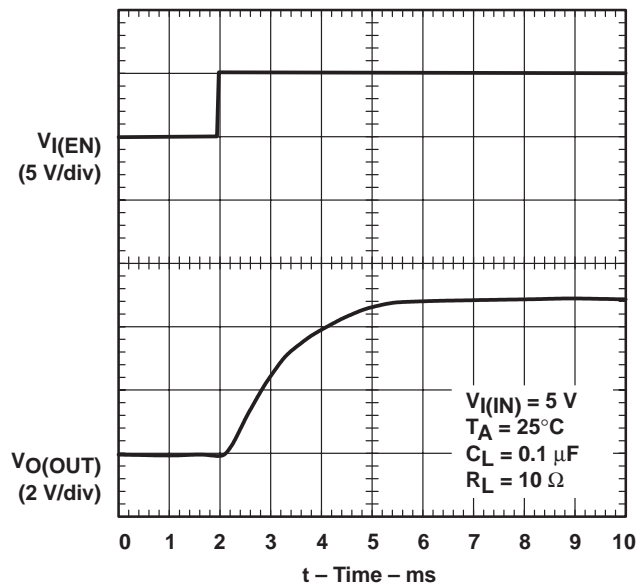


Figure 2. Turnon Delay and Rise Time  
 with 0.1- $\mu\text{F}$  Load

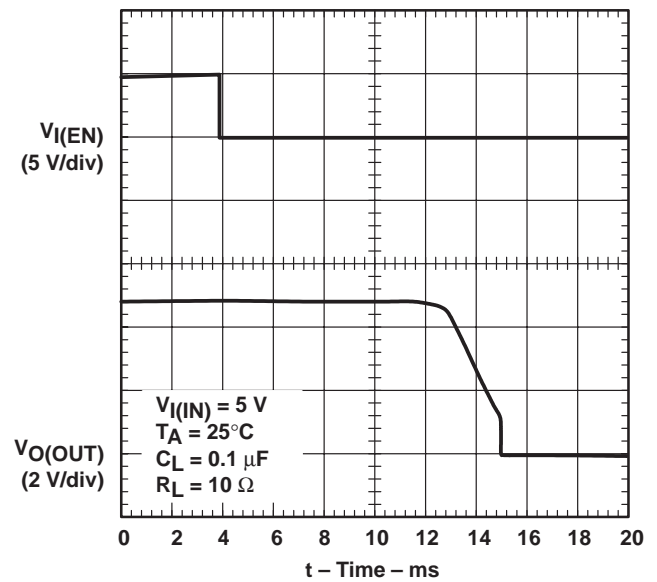


Figure 3. Turnoff Delay and Fall Time  
 with 0.1- $\mu\text{F}$  Load

## PARAMETER MEASUREMENT INFORMATION

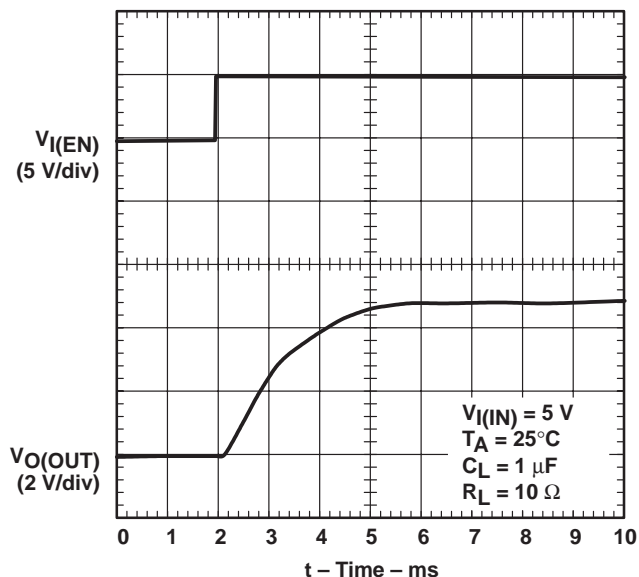


Figure 4. Turnon Delay and Rise Time  
with 1-μF Load

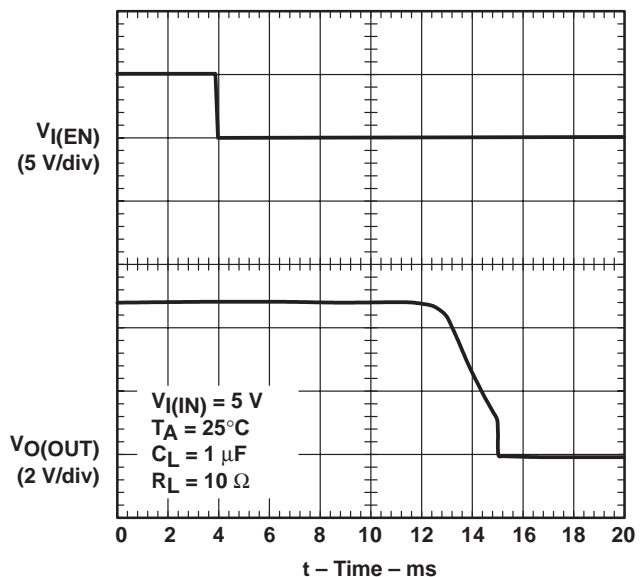


Figure 5. Turnoff Delay and Fall Time  
with 1-μF Load

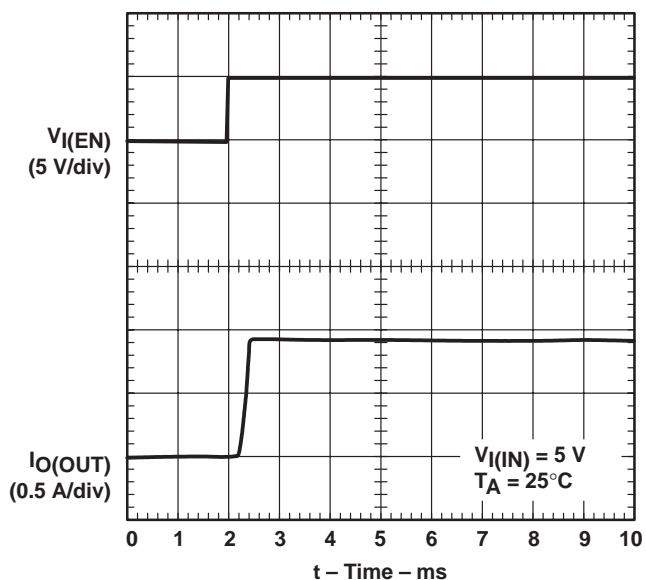


Figure 6. TPS2051A, Short-Circuit Current,  
Device Enabled into Short

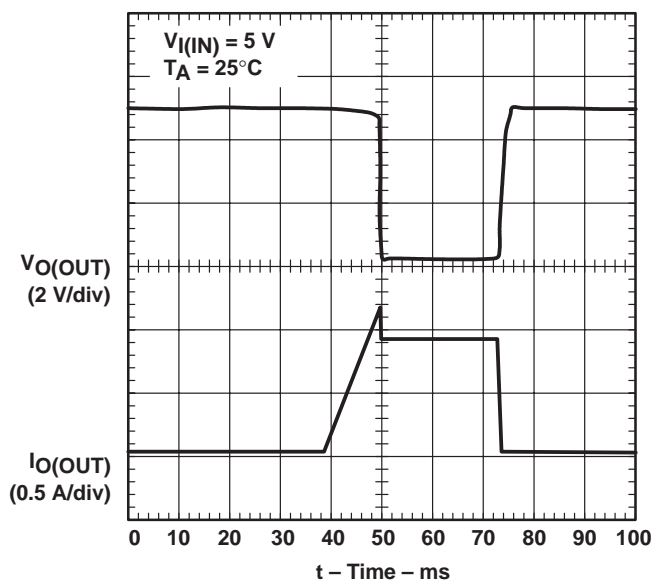


Figure 7. TPS2051A, Threshold Trip Current  
with Ramped Load on Enabled Device

## PARAMETER MEASUREMENT INFORMATION

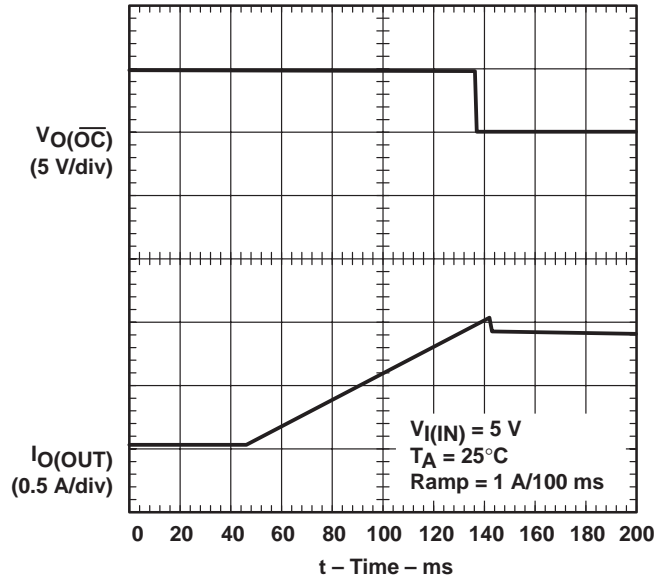


Figure 8. OC Response With Ramped Load on Enabled Device

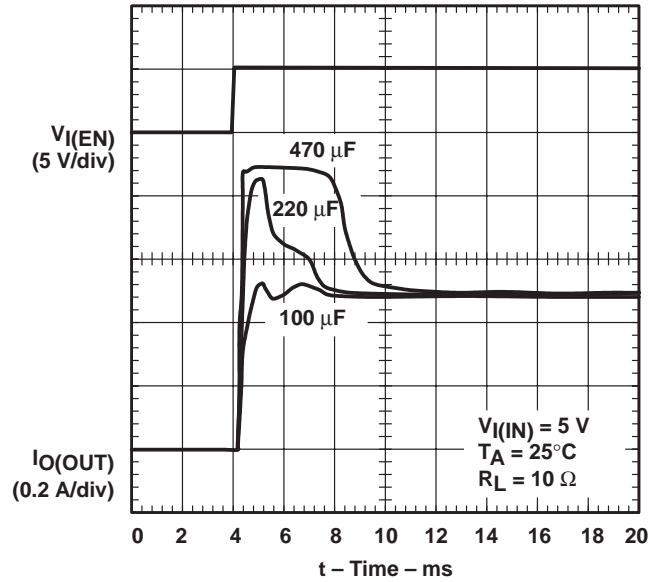


Figure 9. Inrush Current with 100- $\mu\text{F}$ , 220- $\mu\text{F}$  and 470- $\mu\text{F}$  Load Capacitance

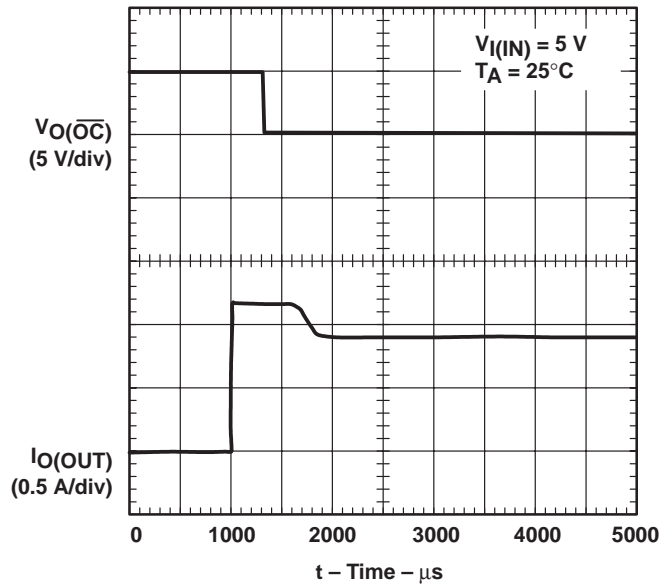


Figure 10. 4- $\Omega$  Load Connected to Enabled Device

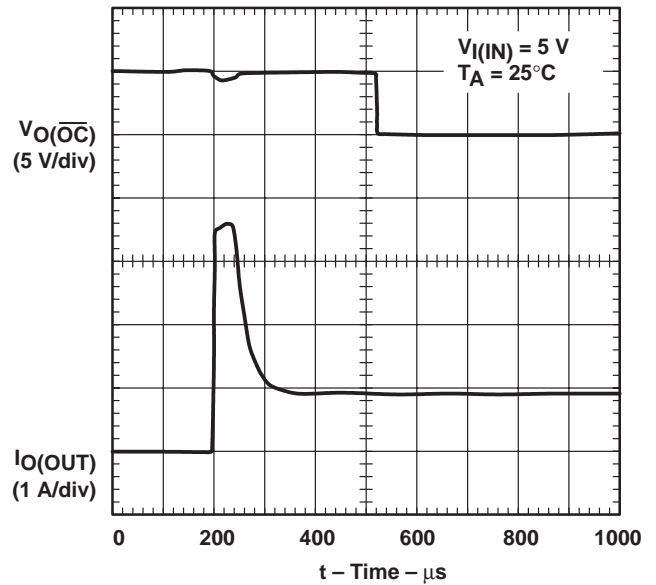


Figure 11. 1- $\Omega$  Load Connected to Enabled Device

## TYPICAL CHARACTERISTICS

TURNON DELAY TIME  
 vs  
 INPUT VOLTAGE

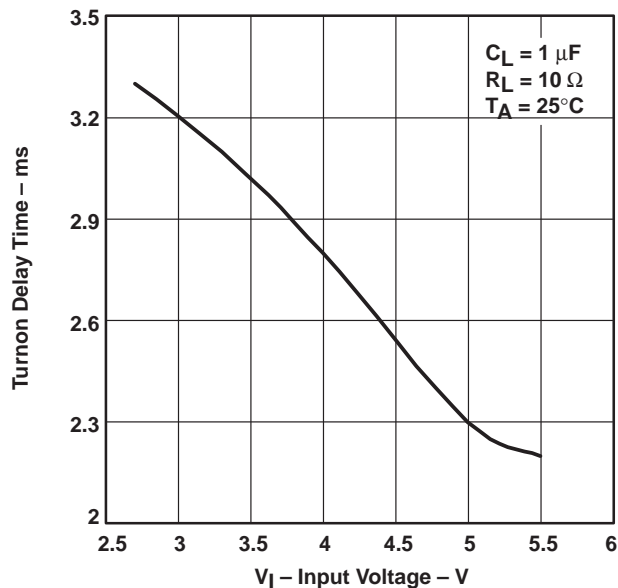


Figure 12

TURNOFF DELAY TIME  
 vs  
 INPUT VOLTAGE

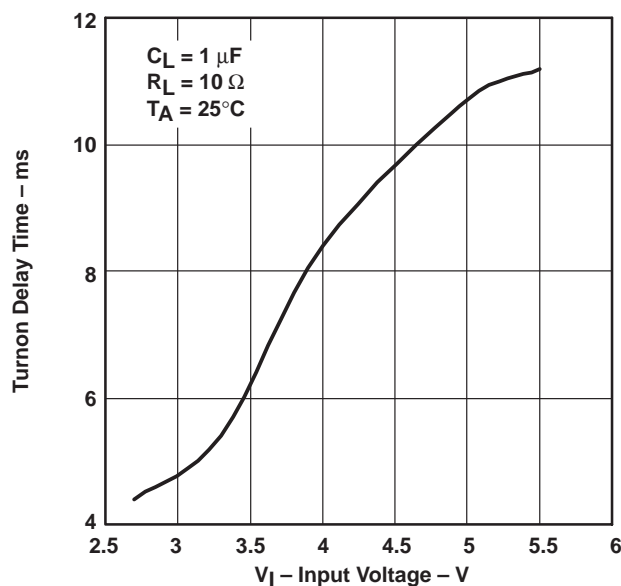


Figure 13

RISE TIME  
 vs  
 INPUT VOLTAGE

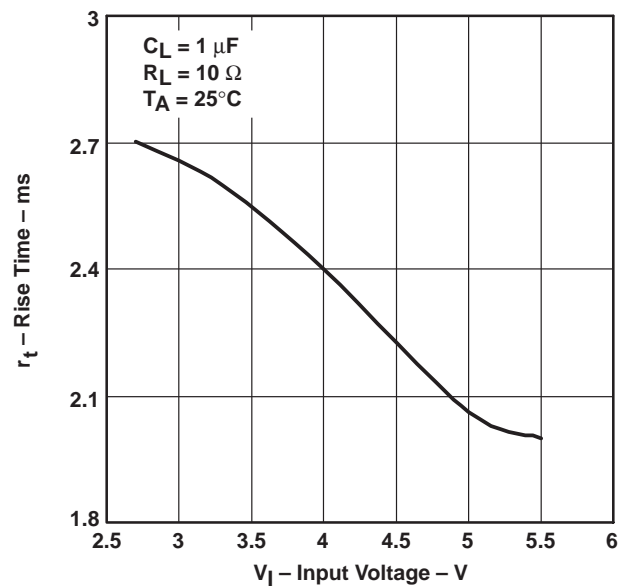


Figure 14

FALL TIME  
 vs  
 INPUT VOLTAGE

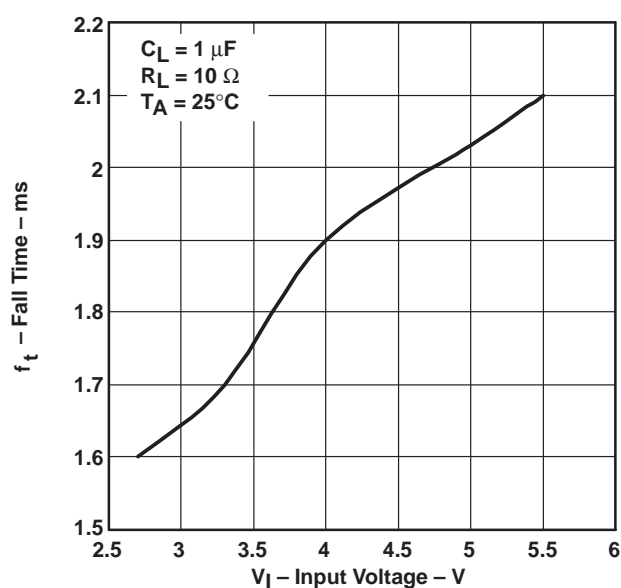


Figure 15



## TYPICAL CHARACTERISTICS

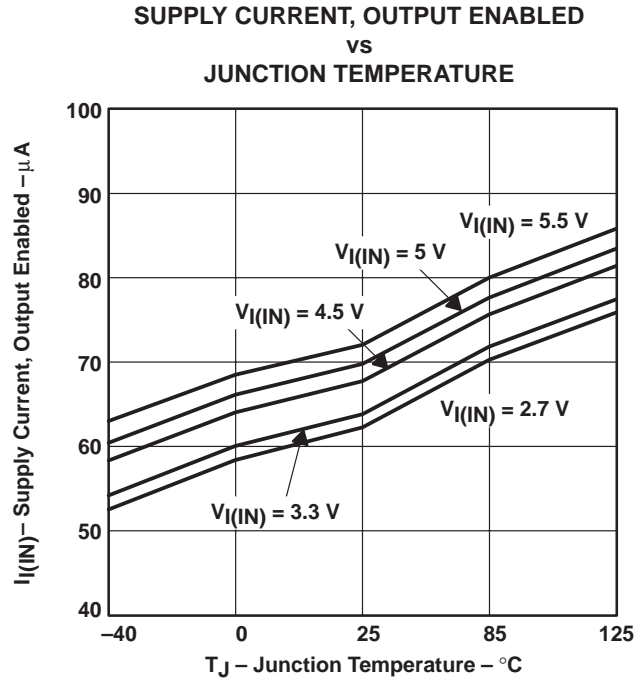


Figure 16

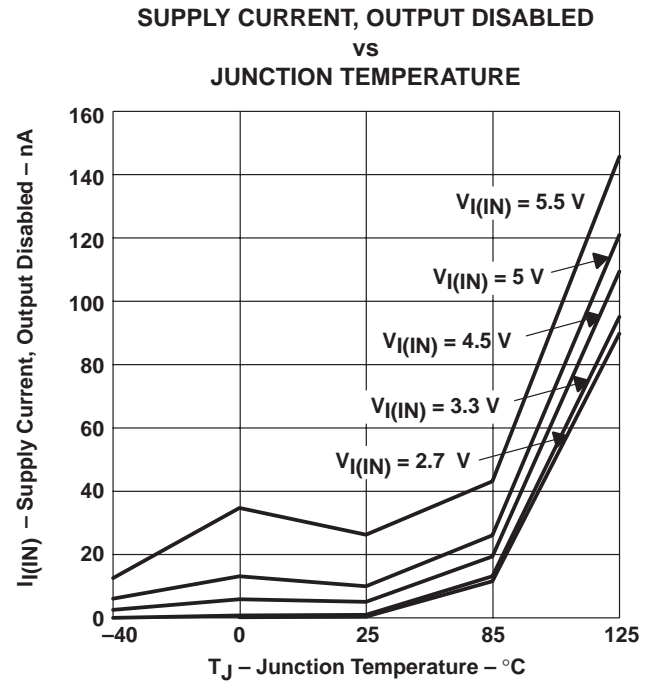


Figure 17

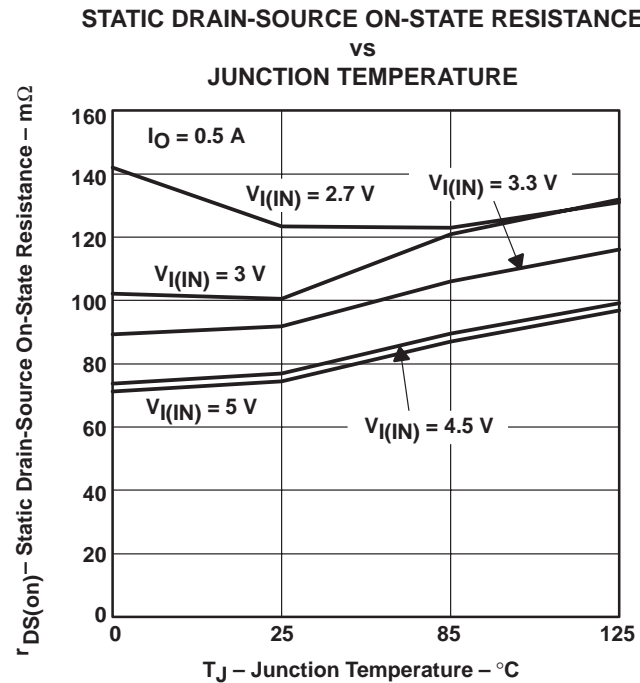


Figure 18

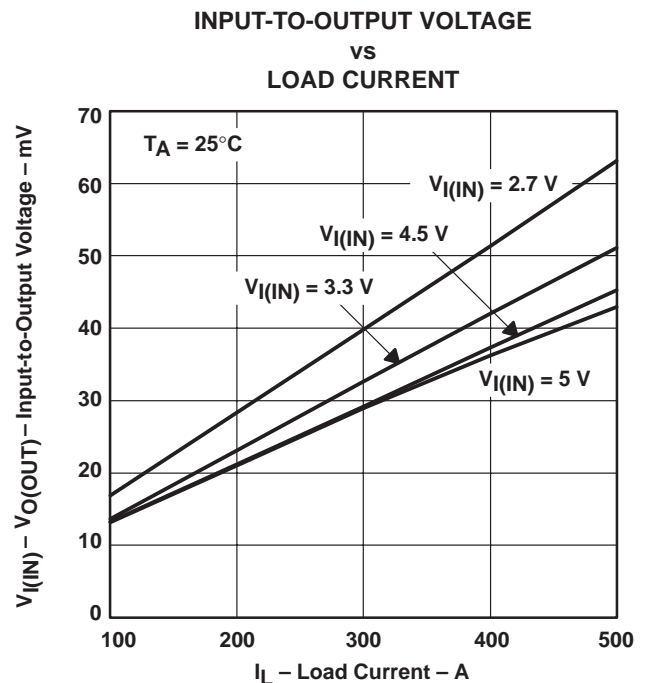


Figure 19

TYPICAL CHARACTERISTICS

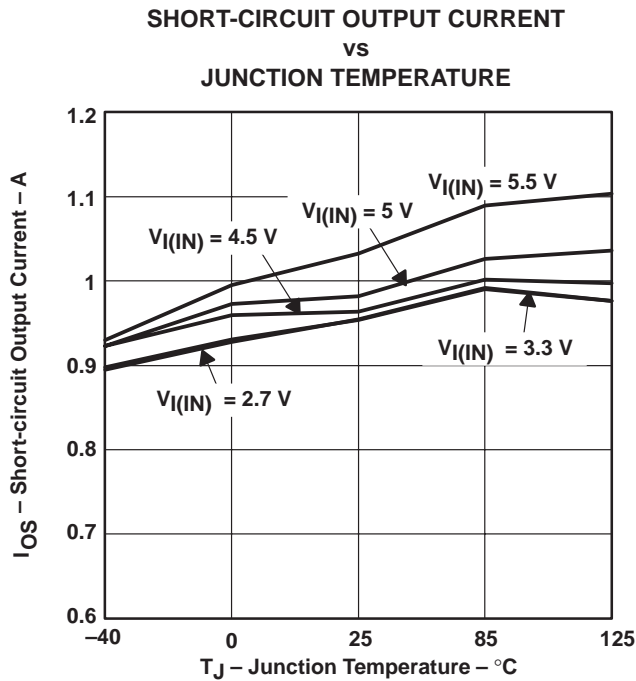


Figure 20

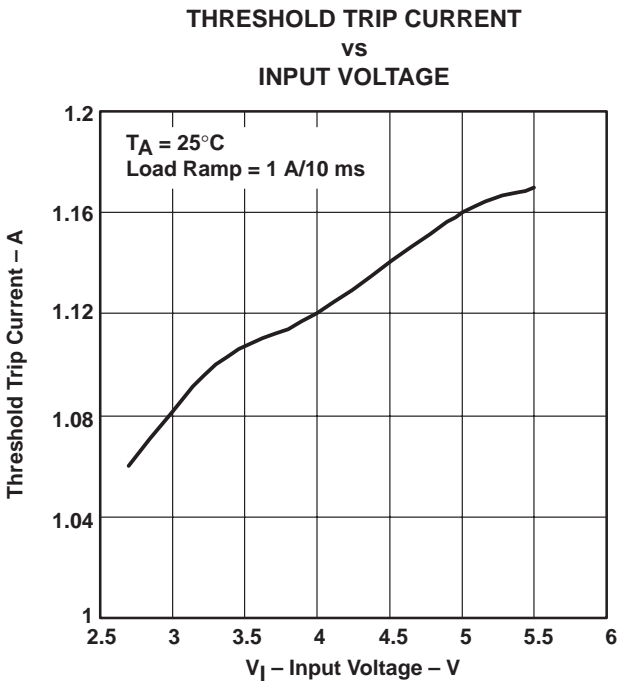


Figure 21

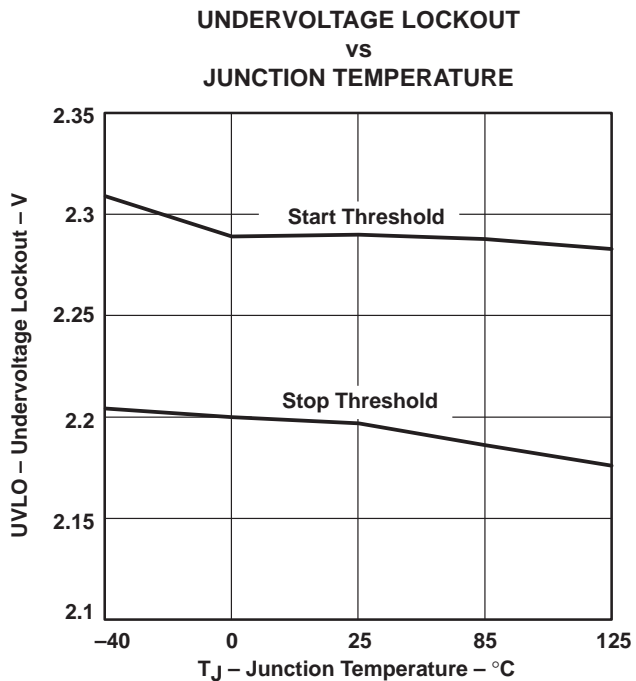


Figure 22

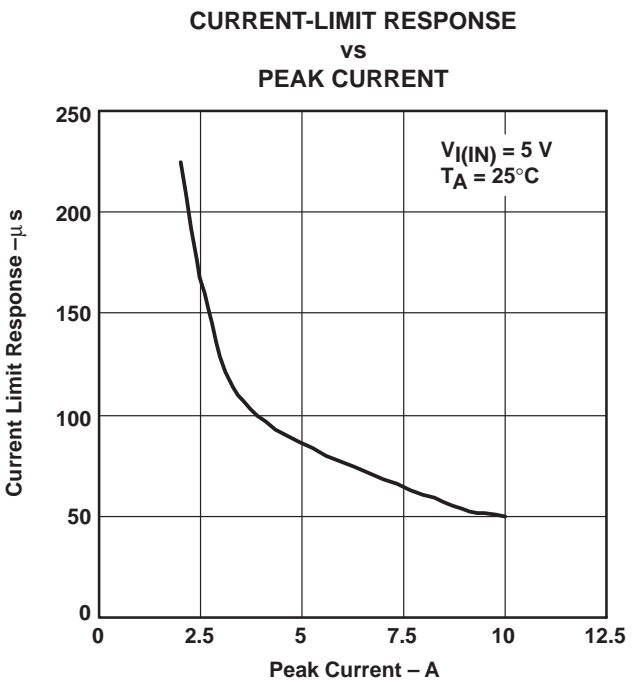


Figure 23

## APPLICATION INFORMATION

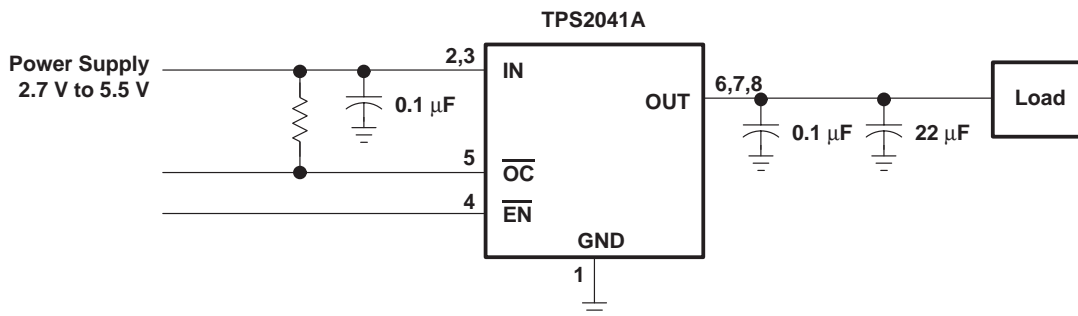


Figure 24. Typical Application (Example, TPS2041A)

### power-supply considerations

A 0.01- $\mu$ F to 0.1- $\mu$ F ceramic bypass capacitor between INx and GND, close to the device, is recommended. Placing a high-value electrolytic capacitor on the output pin(s) is recommended when the output load is heavy. This precaution reduces power-supply transients that may cause ringing on the input. Additionally, bypassing the output with a 0.01- $\mu$ F to 0.1- $\mu$ F ceramic capacitor improves the immunity of the device to short-circuit transients.

### overcurrent

A sense FET is employed to check for overcurrent conditions. Unlike current-sense resistors, sense FETs do not increase the series resistance of the current path. When an overcurrent condition is detected, the device maintains a constant output current and reduces the output voltage accordingly. Complete shutdown occurs only if the fault is present long enough to activate thermal limiting.

Three possible overload conditions can occur. In the first condition, the output has been shorted before the device is enabled or before  $V_{I(IN)}$  has been applied (see Figure 6). The TPS204xA and TPS205xA sense the short and immediately switch into a constant-current output.

In the second condition, a short or an overload occurs while the device is enabled. At the instant the overload occurs, very high currents may flow for a short time before the current-limit circuit can react. After the current-limit circuit has tripped (reached the overcurrent trip threshold) the device switches into constant-current mode.

In the third condition, the load has been gradually increased beyond the recommended operating current. The current is permitted to rise until the current-limit threshold is reached or until the thermal limit of the device is exceeded (see Figure 7). The TPS204xA and TPS205xA are capable of delivering current up to the current-limit threshold without damaging the device. Once the threshold has been reached, the device switches into its constant-current mode.

### $\overline{OC}$ response

The  $\overline{OC}$  open-drain output is asserted (active low) when an overcurrent or overtemperature condition is encountered. The output will remain asserted until the overcurrent or overtemperature condition is removed. Connecting a heavy capacitive load to an enabled device can cause momentary false overcurrent reporting from the inrush current flowing through the device, charging the downstream capacitor. The TPS204xA and TPS205xA family of devices are designed to reduce false overcurrent reporting. An internal overcurrent transient filter eliminates the need for external components to remove unwanted pulses. Using low-ESR electrolytic capacitors on the output lowers the inrush current flow through the device during hot-plug events by providing a low-impedance energy source, also reducing erroneous overcurrent reporting.

TPS2041A, TPS2042A, TPS2043A, TPS2044A  
 TPS2051A, TPS2052A, TPS2053A, TPS2054A  
**CURRENT-LIMITED POWER-DISTRIBUTION SWITCHES**

SLVS247 – SEPTEMBER 2000

## APPLICATION INFORMATION

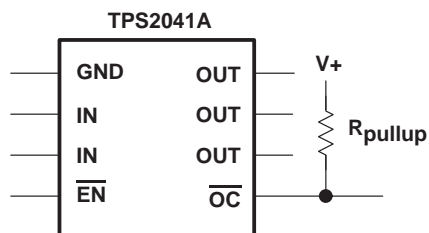


Figure 25. Typical Circuit for  $\overline{OC}$  Pin (Example, TPS2041A)

### power dissipation and junction temperature

The low on-resistance on the n-channel MOSFET allows small surface-mount packages, such as SOIC, to pass large currents. The thermal resistances of these packages are high compared to those of power packages; it is good design practice to check power dissipation and junction temperature. Begin by determining the  $r_{DS(on)}$  of the N-channel MOSFET relative to the input voltage and operating temperature. As an initial estimate, use the highest operating ambient temperature of interest and read  $r_{DS(on)}$  from Figure 18. Using this value, the power dissipation per switch can be calculated by:

$$P_D = r_{DS(on)} \times I^2$$

Depending on which device is being used, multiply this number by the number of switches being used. This step will render the total power dissipation from the N-channel MOSFETs.

Finally, calculate the junction temperature:

$$T_J = P_D \times R_{\theta JA} + T_A$$

Where:

$T_A$  = Ambient Temperature °C

$R_{\theta JA}$  = Thermal resistance SOIC = 172°C/W (for 8 pin), 111°C/W (for 16 pin)

$P_D$  = Total power dissipation based on number of switches being used.

Compare the calculated junction temperature with the initial estimate. If they do not agree within a few degrees, repeat the calculation, using the calculated value as the new estimate. Two or three iterations are generally sufficient to get a reasonable answer.

### thermal protection

Thermal protection prevents damage to the IC when heavy-overload or short-circuit faults are present for extended periods of time. The faults force the TPS204xA and TPS205xA into constant-current mode, which causes the voltage across the high-side switch to increase; under short-circuit conditions, the voltage across the switch is equal to the input voltage. The increased dissipation causes the junction temperature to rise to high levels. The protection circuit senses the junction temperature of the switch and shuts it off. Hysteresis is built into the thermal sense circuit, and after the device has cooled approximately 20 degrees, the switch turns back on. The switch continues to cycle in this manner until the load fault or input power is removed.

The TPS204xA and TPS205xA implement a dual thermal trip to allow fully independent operation of the power distribution switches. In an overcurrent or short-circuit condition the junction temperature will rise. Once the die temperature rises to approximately 140°C, the internal thermal sense circuitry checks which power switch is in an overcurrent condition and turns that power switch off, thus isolating the fault without interrupting operation of the adjacent power switch. Should the die temperature exceed the first thermal trip point of 140°C and reach 160°C, both switches turn off. The  $\overline{OC}$  open-drain output is asserted (active low) when overtemperature or overcurrent occurs.

## APPLICATION INFORMATION

### undervoltage lockout (UVLO)

An undervoltage lockout ensures that the power switch is in the off state at power up. Whenever the input voltage falls below approximately 2 V, the power switch will be quickly turned off. This facilitates the design of hot-insertion systems where it is not possible to turn off the power switch before input power is removed. The UVLO will also keep the switch from being turned on until the power supply has reached at least 2 V, even if the switch is enabled. Upon reinsertion, the power switch will be turned on, with a controlled rise time to reduce EMI and voltage overshoots.

### universal serial bus (USB) applications

The universal serial bus (USB) interface is a 12-Mb/s, or 1.5-Mb/s, multiplexed serial bus designed for low-to-medium bandwidth PC peripherals (e.g., keyboards, printers, scanners, and mice). The four-wire USB interface is conceived for dynamic attach-detach (hot plug-unplug) of peripherals. Two lines are provided for differential data, and two lines are provided for 5-V power distribution.

USB data is a 3.3-V level signal, but power is distributed at 5 V to allow for voltage drops in cases where power is distributed through more than one hub across long cables. Each function must provide its own regulated 3.3 V from the 5-V input or its own internal power supply.

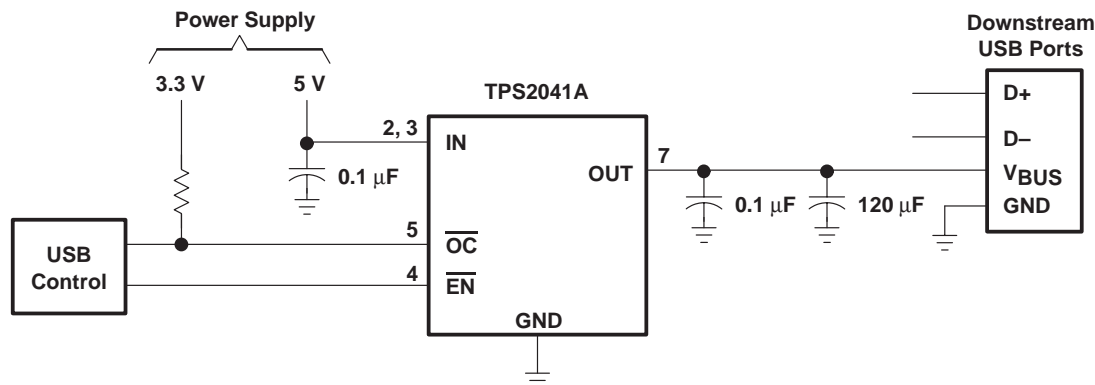
The USB specification defines the following five classes of devices, each differentiated by power-consumption requirements:

- Hosts/self-powered hubs (SPH)
- Bus-powered hubs (BPH)
- Low-power, bus-powered functions
- High-power, bus-powered functions
- Self-powered functions

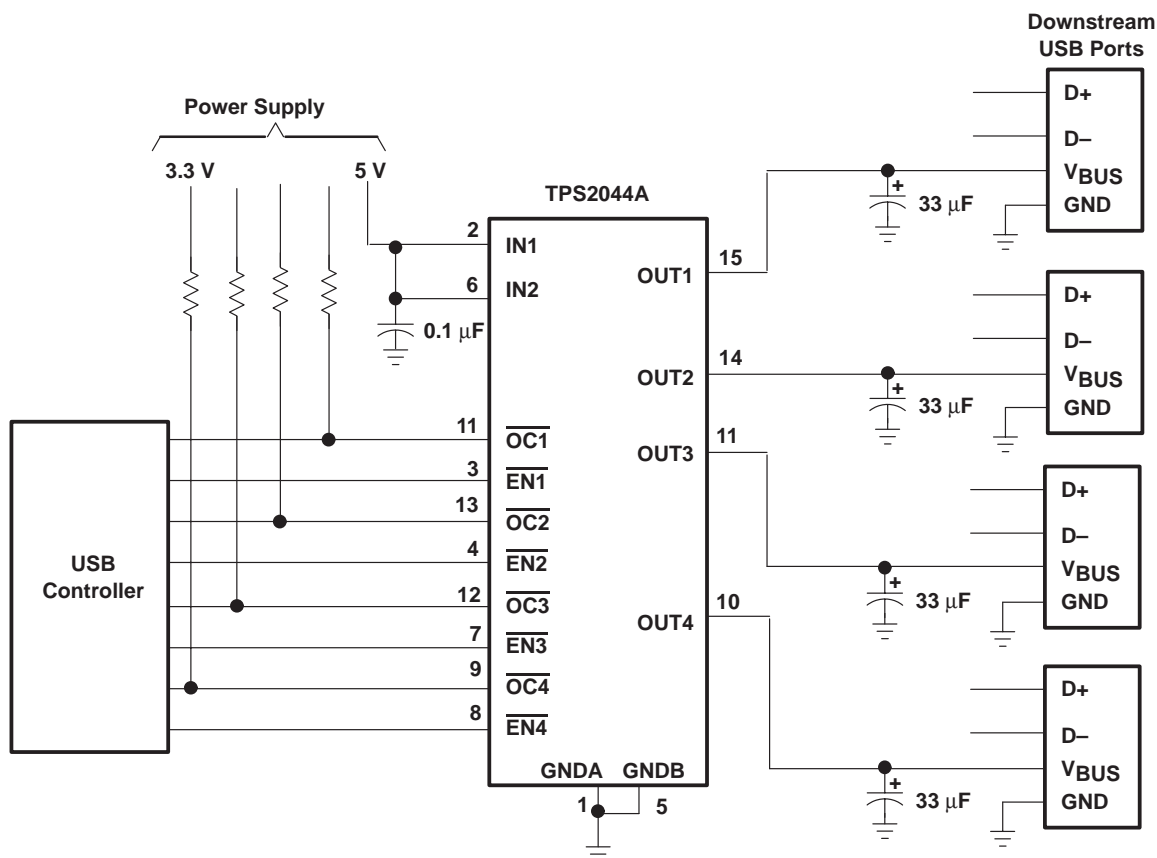
Self-powered and bus-powered hubs distribute data and power to downstream functions. The TPS204xA and TPS205xA can provide power-distribution solutions for many of these classes of devices.

### host/self-powered and bus-powered hubs

Hosts and self-powered hubs have a local power supply that powers the embedded functions and the downstream ports (see Figures 26 and 27). This power supply must provide from 5.25 V to 4.75 V to the board side of the downstream connection under full-load and no-load conditions. Hosts and SPHs are required to have current-limit protection and must report overcurrent conditions to the USB controller. Typical SPHs are desktop PCs, monitors, printers, and stand-alone hubs.



## APPLICATION INFORMATION



**Figure 27. Typical Four-Port USB Host/Self-Powered Hub**

Bus-powered hubs obtain all power from upstream ports and often contain an embedded function. The hubs are required to power up with less than one unit load. The BPH usually has one embedded function, and power is always available to the controller of the hub. If the embedded function and hub require more than 100 mA on powerup, the power to the embedded function may need to be kept off until enumeration is completed. This can be accomplished by removing power or by shutting off the clock to the embedded function. Power switching the embedded function is not necessary if the aggregate power draw for the function and controller is less than one unit load. The total current drawn by the bus-powered device is the sum of the current to the controller, the embedded function, and the downstream ports, and it is limited to 500 mA from an upstream port.

## APPLICATION INFORMATION

### low-power bus-powered functions and high-power bus-powered functions

Both low-power and high-power bus-powered functions obtain all power from upstream ports; low-power functions always draw less than 100 mA; high-power functions must draw less than 100 mA at power up and can draw up to 500 mA after enumeration. If the load of the function is more than the parallel combination of 44  $\Omega$  and 10  $\mu\text{F}$  at power up, the device must implement inrush current limiting (see Figure 28).

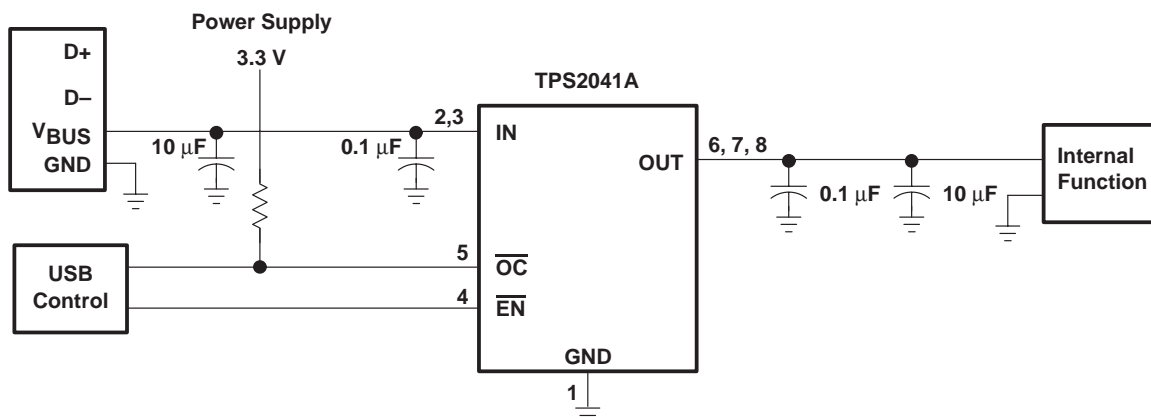


Figure 28. High-Power Bus-Powered Function (Example, TPS2041A)

### USB power-distribution requirements

USB can be implemented in several ways, and, regardless of the type of USB device being developed, several power-distribution features must be implemented.

- Hosts/self-powered hubs must:
  - Current-limit downstream ports
  - Report overcurrent conditions on USB  $V_{\text{BUS}}$
- Bus-powered hubs must:
  - Enable/disable power to downstream ports
  - Power up at <100 mA
  - Limit inrush current (<44  $\Omega$  and 10  $\mu\text{F}$ )
- Functions must:
  - Limit inrush currents
  - Power up at <100 mA

The feature set of the TPS204xA and TPS205xA allows them to meet each of these requirements. The integrated current-limiting and overcurrent reporting is required by hosts and self-powered hubs. The logic-level enable and controlled rise times meet the need of both input and output ports on bus-power hubs, as well as the input ports for bus-power functions (see Figures 29 through 32).

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**TUSB2040**  
**Hub Controller**



**Figure 29. Hybrid Self/Bus-Powered Hub Implementation, TPS2041A**



## TUSB2040 Hub Controller



**Figure 30. Hybrid Self/Bus-Powered Hub Implementation, TPS2042A**

## SLVS247 – SEPTEMBER 2000

**TUSB2040**  
**Hub Controller**



**Figure 31. Hybrid Self/Bus-Powered Hub Implementation, TPS2043A**

## APPLICATION INFORMATION

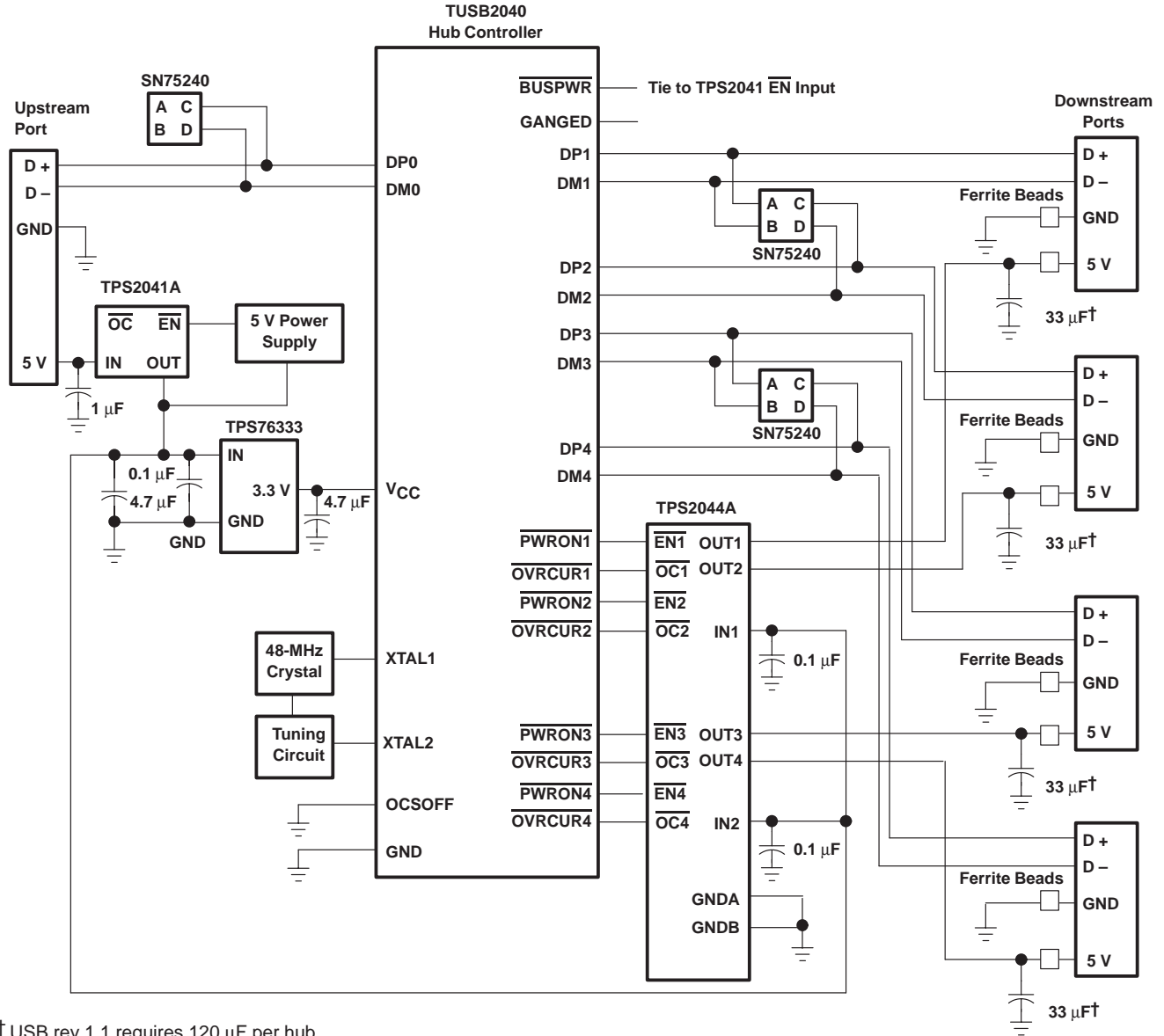


Figure 32. Hybrid Self/Bus-Powered Hub Implementation, TPS2044A

By placing the TPS204xA and TPS205xA between the  $V_{CC}$  input and the rest of the circuitry, the input power will reach these devices first after insertion. The typical rise time of the switch is approximately 2.5 ms, providing a slow voltage ramp at the output of the device. This implementation controls system surge currents and provides a hot-plugging mechanism for any device.

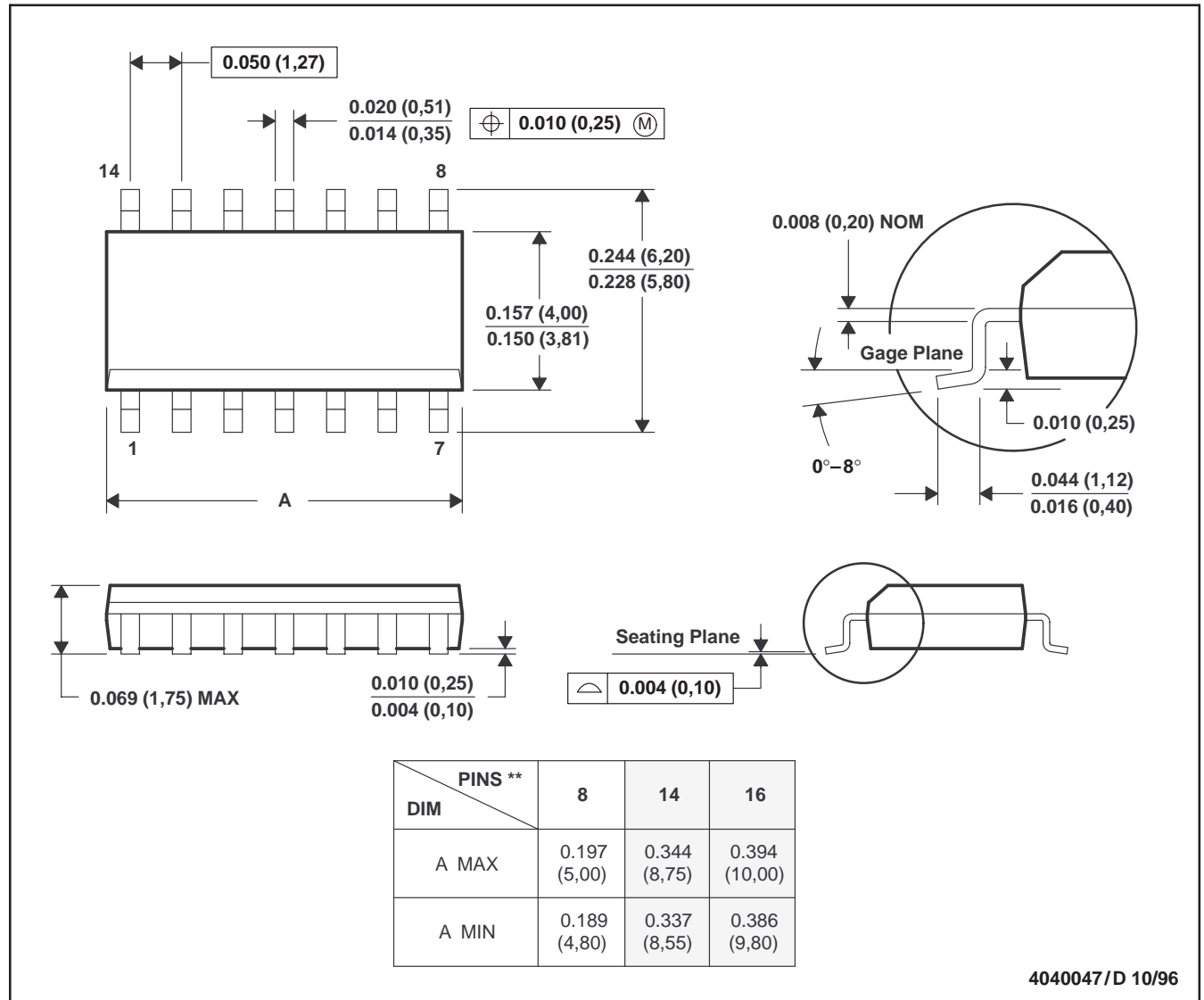
TPS2041A, TPS2042A, TPS2043A, TPS2044A  
 TPS2051A, TPS2052A, TPS2053A, TPS2054A  
 CURRENT-LIMITED POWER-DISTRIBUTION SWITCHES  
 SLVS247 – SEPTEMBER 2000

MECHANICAL DATA

D (R-PDSO-G\*\*)

PLASTIC SMALL-OUTLINE PACKAGE

14 PIN SHOWN



- NOTES: A. All linear dimensions are in inches (millimeters).  
 B. This drawing is subject to change without notice.  
 C. Body dimensions do not include mold flash or protrusion, not to exceed 0.006 (0,15).  
 D. Falls within JEDEC MS-012

# PACKAGE OPTION ADDENDUM

4-Nov-2005

## PACKAGING INFORMATION

Orderable Device	Status <sup>(1)</sup>	Package Type	Package Drawing	Pins	Package Qty	Eco Plan <sup>(2)</sup>	Lead/Ball Finish	MSL Peak Temp <sup>(3)</sup>
TPS2041AD	NRND	SOIC	D	8	75	Green (RoHS & no Sb/Br)	CU NIPDAU	Level-1-260C-UNLIM
TPS2041ADG4	NRND	SOIC	D	8	75	Green (RoHS & no Sb/Br)	CU NIPDAU	Level-1-260C-UNLIM
TPS2041ADR	NRND	SOIC	D	8	2500	Green (RoHS & no Sb/Br)	CU NIPDAU	Level-1-260C-UNLIM
TPS2041ADRG4	NRND	SOIC	D	8	2500	Green (RoHS & no Sb/Br)	CU NIPDAU	Level-2-260C-1 YEAR
TPS2042AD	NRND	SOIC	D	8	75	Green (RoHS & no Sb/Br)	CU NIPDAU	Level-1-260C-UNLIM
TPS2042ADG4	NRND	SOIC	D	8	75	Green (RoHS & no Sb/Br)	CU NIPDAU	Level-1-260C-UNLIM
TPS2042ADR	NRND	SOIC	D	8	2500	Green (RoHS & no Sb/Br)	CU NIPDAU	Level-1-260C-UNLIM
TPS2042ADRG4	NRND	SOIC	D	8	2500	Green (RoHS & no Sb/Br)	CU NIPDAU	Level-2-260C-1 YEAR
TPS2043AD	NRND	SOIC	D	16	40	Green (RoHS & no Sb/Br)	CU NIPDAU	Level-1-260C-UNLIM
TPS2043ADG4	NRND	SOIC	D	16	40	Green (RoHS & no Sb/Br)	CU NIPDAU	Level-1-260C-UNLIM
TPS2043ADR	NRND	SOIC	D	16	2500	Green (RoHS & no Sb/Br)	CU NIPDAU	Level-1-260C-UNLIM
TPS2043ADRG4	NRND	SOIC	D	16	2500	Green (RoHS & no Sb/Br)	CU NIPDAU	Level-1-260C-UNLIM
TPS2044AD	NRND	SOIC	D	16	40	Green (RoHS & no Sb/Br)	CU NIPDAU	Level-1-260C-UNLIM
TPS2044ADR	NRND	SOIC	D	16	2500	Green (RoHS & no Sb/Br)	CU NIPDAU	Level-1-260C-UNLIM
TPS2044ADRG4	NRND	SOIC	D	16	2500	Green (RoHS & no Sb/Br)	CU NIPDAU	Level-1-260C-UNLIM
TPS2051AD	NRND	SOIC	D	8	75	Green (RoHS & no Sb/Br)	CU NIPDAU	Level-1-260C-UNLIM
TPS2051ADR	NRND	SOIC	D	8	2500	Green (RoHS & no Sb/Br)	CU NIPDAU	Level-1-260C-UNLIM
TPS2051ADRG4	NRND	SOIC	D	8	2500	Green (RoHS & no Sb/Br)	CU NIPDAU	Level-1-260C-UNLIM
TPS2052AD	NRND	SOIC	D	8	75	Green (RoHS & no Sb/Br)	CU NIPDAU	Level-1-260C-UNLIM
TPS2052ADG4	NRND	SOIC	D	8	75	Green (RoHS & no Sb/Br)	CU NIPDAU	Level-1-260C-UNLIM
TPS2052ADR	NRND	SOIC	D	8	2500	Green (RoHS & no Sb/Br)	CU NIPDAU	Level-1-260C-UNLIM
TPS2052ADRG4	NRND	SOIC	D	8	2500	Green (RoHS & no Sb/Br)	CU NIPDAU	Level-1-260C-UNLIM
TPS2053AD	NRND	SOIC	D	16	40	Green (RoHS & no Sb/Br)	CU NIPDAU	Level-1-260C-UNLIM
TPS2053ADR	NRND	SOIC	D	16	2500	Green (RoHS & no Sb/Br)	CU NIPDAU	Level-1-260C-UNLIM
TPS2053ADRG4	NRND	SOIC	D	16	2500	Green (RoHS & no Sb/Br)	CU NIPDAU	Level-1-260C-UNLIM

# PACKAGE OPTION ADDENDUM

4-Nov-2005

Orderable Device	Status <sup>(1)</sup>	Package Type	Package Drawing	Pins	Package Qty	Eco Plan <sup>(2)</sup>	Lead/Ball Finish	MSL Peak Temp <sup>(3)</sup>
TPS2054AD	NRND	SOIC	D	16	40	Green (RoHS & no Sb/Br)	CU NIPDAU	Level-1-260C-UNLIM
TPS2054ADR	NRND	SOIC	D	16	2500	Green (RoHS & no Sb/Br)	CU NIPDAU	Level-1-260C-UNLIM
TPS2054ADRG4	NRND	SOIC	D	16	2500	Green (RoHS & no Sb/Br)	CU NIPDAU	Level-1-260C-UNLIM

<sup>(1)</sup> The marketing status values are defined as follows:

**ACTIVE:** Product device recommended for new designs.

**LIFEBUY:** TI has announced that the device will be discontinued, and a lifetime-buy period is in effect.

**NRND:** Not recommended for new designs. Device is in production to support existing customers, but TI does not recommend using this part in a new design.

**PREVIEW:** Device has been announced but is not in production. Samples may or may not be available.

**OBSOLETE:** TI has discontinued the production of the device.

<sup>(2)</sup> Eco Plan - The planned eco-friendly classification: Pb-Free (RoHS) or Green (RoHS & no Sb/Br) - please check <http://www.ti.com/productcontent> for the latest availability information and additional product content details.

**TBD:** The Pb-Free/Green conversion plan has not been defined.

**Pb-Free (RoHS):** TI's terms "Lead-Free" or "Pb-Free" mean semiconductor products that are compatible with the current RoHS requirements for all 6 substances, including the requirement that lead not exceed 0.1% by weight in homogeneous materials. Where designed to be soldered at high temperatures, TI Pb-Free products are suitable for use in specified lead-free processes.

**Green (RoHS & no Sb/Br):** TI defines "Green" to mean Pb-Free (RoHS compatible), and free of Bromine (Br) and Antimony (Sb) based flame retardants (Br or Sb do not exceed 0.1% by weight in homogeneous material)

<sup>(3)</sup> MSL, Peak Temp. -- The Moisture Sensitivity Level rating according to the JEDEC industry standard classifications, and peak solder temperature.

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